NSN 5962-01-493-4387

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
TANK-,A-BRA-MSM1
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
80.00 milliamperes total supply
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital memory, 128k x 8 bit eeprom
Voltage Rating And Type Per Characteristic:
6.0 volts total supply
Time Rating Per Chacteristic:
150.00 nanoseconds input to output access
Memory Device Type:
Eeprom
Nuclear Hardness Critical Feature:
Hardened
Terminal Type And Quantity:
32 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
A458a0